SSL2102 Mains LED driver IC for dimmable LED lighting Rev. 01 – 29 June 2009 P

Product data sheet

1. General description

The SSL2102 is a Switched Mode Power Supply (SMPS) controller IC that operates in combination with a phase cut dimmer directly from rectified mains. It is designed to drive LED devices. The device includes a high-voltage power switch and a circuit to allow direct start-up from the rectified mains voltage. Furthermore the device includes high-voltage circuitry to supply the phase cut dimmer.

For dimmer applications, integrated dedicated circuitry optimizes the dimming curve.

2. Features

- Easy migration to existing lighting control infrastructure, TRIAC and transistor dimmers
- Supports majority of available dimming solutions
- Valley switching efficiency is optimized by dedicated built-in circuitry
- Built-in demagnetization detection
- The IC has Over Temperature Protection (OTP) built-in
- Short-Winding Protection (SWP) and Over Current Protection (OCP)
- The IC has internal V_{CC} generation that allows start-up from rectified mains voltage
- Natural dimming curve by logarithmic correction
- Limited external components required due to high integration level
- Thermal enhanced SO20 wide body package.

3. Applications

The SSL2102 is suitable for high efficiency and high power factor SSL applications below 25 W, these include:

- SSL retro-fit lamps (e.g. GU10, E27) from 8 W to 15 W.
- LED modules, separate power supplies, e.g. LED spots, down-lights from 15 W to 25 W
- LED strings, e.g. retail display up to a maximum of 25 W

For power ratings below 15 W (for LED modules) and 8 W (for SSL retrofit) NXP offers the SSL2101.



4. Quick reference data

Quick reference data					
Parameter	Conditions	Min	Тур	Max	Unit
drain-source on-state	power switch; I _{SOURCE} =	= -0.50	A		
resistance	T _j = 25 °C	4.5	6.5	7.5	Ω
	$I_{\text{SOURCE}} = -0.20 \text{ A}$				
	T _j = 125 °C	-	9.5	10	Ω
supply voltage		8.5	-	40	V
oscillator frequency		10	100	200	kHz
current on pin DRAIN	V _{DRAIN} > 60 V; no auxiliary supply	-	-	2.2	mA
	V _{DRAIN} > 60 V; with auxiliary supply	-	30	125	μA
voltage on pin DRAIN		40	-	600	V
minimum duty factor		-	0	-	%
maximum duty cycle		-	75	-	%
ambient temperature		-40	-	+100	°C
	Parameter drain-source on-state resistance supply voltage oscillator frequency current on pin DRAIN voltage on pin DRAIN minimum duty factor maximum duty cycle	ParameterConditionsdrain-source on-state resistancepower switch; I_{SOURCE} $T_j = 25 \ ^C$ $I_{SOURCE} = -0.20 \ ^A$ $T_j = 125 \ ^C$ $I_{T_j} = 125 \ ^C$ supply voltage $V_{DRAIN} > 60 \ ^C$; no auxiliary supplycurrent on pin DRAIN $V_{DRAIN} > 60 \ ^C$; with auxiliary supplyvoltage on pin DRAIN $V_{DRAIN} > 60 \ ^C$; with auxiliary supplyvoltage on pin DRAIN $V_{DRAIN} > 60 \ ^C$; minimum duty factormaximum duty cycle $V_{DRAIN} > 60 \ ^C$	ParameterConditionsMindrain-source on-state resistancepower switch; $I_{SOURCE} = -0.50$ $T_j = 25 \ ^C$ 4.5 $I_{SOURCE} = -0.20 \ A$ $I_{SOURCE} = -0.20 \ A$ supply voltage8.5oscillator frequency10current on pin DRAIN $V_{DRAIN} > 60 \ V$; no auxiliary supplyvoltage on pin DRAIN40minimum duty factor-maximum duty cycle-	ParameterConditionsMinTypdrain-source on-state resistancepower switch; $I_{SOURCE} = -0.50$ -0.50 -0.50 $T_j = 25 °C$ 4.5 6.5 $I_{SOURCE} = -0.20 A$ $T_j = 125 °C$ -0.50 supply voltage 8.5 -0.50 oscillator frequency 10 100 current on pin DRAIN $V_{DRAIN} > 60 V$; no auxiliary supply -0.50 voltage on pin DRAIN 400 -0.50 voltage on pin DRAIN -0.50 -0.50 minimum duty factor -0.50 -0.50 maximum duty cycle -0.50 -0.50	Parameter Conditions Min Typ Max drain-source on-state resistance power switch; $I_{SOURCE} = -0.50 \times 10^{-1}$ $T_j = 25 \circ C$ 4.5 6.5 7.5 $I_{SOURCE} = -0.20 A$ $I_j = 125 \circ C$ $ 9.5$ 10^{-1} supply voltage $I_j = 125 \circ C$ $ 9.5$ 10^{-1} oscillator frequency $I^{-1} = 125 \circ C$ $10^{-1} = 125 \circ C$

5. Ordering information

Table 2.Ordering information

Type number	Package	Package					
	Name	Description	Version				
SSL2102T	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1				

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6. Block diagram



7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3.	Pin description
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	escription	
Symbol	Pin	Description
SBLEED	1	drain of internal strong bleeder switch
GND	2	ground
GND	3	ground
WBLEED	4	drain of internal weak bleeder switch
V _{CC}	5	supply voltage
GND	6	ground
GND	7	ground
BRIGHTNESS	8	brightness input
RC2	9	setting for frequency reduction
RC	10	frequency setting
PWMLIMIT	11	PWM limit input
ISENSE	12	current sense input for WBLEED
AUX	13	Input for voltage from auxiliary winding for timing (demagnetization)
GND	14	ground
SOURCE	15	source of internal power switch
GND	16	ground
GND	17	ground
GND	18	ground
GND	19	ground
DRAIN	20	drain of internal power switch; input for start-up current and valley sensing

8. Functional description

The SSL2102 is a LED driver IC that operates directly from the rectified mains.

The SSL2102 uses on-time mode control and frequency control to control the LED brightness. The BRIGHTNESS and PWMLIMIT input of the IC can be used to control the LED light output in combination with an external dimmer. The PWMLIMIT input can also be used for Thermal Lumen Management (TLM) and for precision LED current control.

8.1 Start-up and UnderVoltage LockOut (UVLO)

Initially, the IC is self-supplying from the rectified mains voltage. The IC starts switching as soon as the voltage on pin V_{CC} passes the $V_{CC(startup)}$ level. The supply can be taken over by the auxiliary winding of the transformer as soon as V_{CC} is high enough and the supply from the line is stopped for high efficiency operation. Alternatively the IC can be supplied via a bleeder resistor connected to a high voltage.

Remark: The maximum V_{CC} voltage rating of the IC.

If for some reason the auxiliary supply is not sufficient, the high-voltage supply can also supply the IC. As soon as the voltage on pin V_{CC} drops below the $V_{CC(UVLO)}$ level, the IC stops switching and will restart from the rectified mains voltage, if the internal current delivered is sufficient.

8.2 Oscillator

An internal oscillator inside the IC provides the timing for the switching converter logics.

The frequency of the oscillator is set by the external resistors and the capacitor on pin RC and pin RC2. The external capacitor is charged rapidly to the $V_{RC(max)}$ level and, starting from a new primary stroke, it discharges to the $V_{RC(min)}$ level. Because the discharge is exponential, the relative sensitivity of the duty factor to the regulation voltage at low duty factor is almost equal to the sensitivity at high duty factors. This results in a more constant gain over the duty factor range compared to Pulse Width Modulated (PWM) systems with a linear sawtooth oscillator. Stable operation at low duty factors is easily realized. The frequency of the converter when $V_{BRIGHTNESS}$ is high can be estimated using Equation 1:

$$RC = \frac{1}{3.5} \cdot \left(\frac{1}{f_{osc}} - t_{charge}\right) \tag{1}$$

R equals the parallel resistance of both oscillator resistors. C is the capacitor connected at the RC pin (pin 8).

The BRIGHTNESS input controls the frequency reduction mode. Figure 3 shows that the oscillator switches over from an RC curve with R1//R2 to R1 only. A low BRIGHTNESS voltage will reduce the switching frequency.

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A typical RC waveform is given in <u>Figure 4</u>. The RC switch-over threshold is controlled by the BRIGHTNESS pin.

To ensure that the capacitor can be charged within the charge time, the value of the oscillator capacitor should be limited to 1 nF. Leakage current limits the value of the resistor connected between the RC pin and the ground should be limited to a maximum of 220 k Ω .



8.3 Duty factor control

The duty factor is controlled by an internally regulated voltage and the oscillator signal on pin RC. The internal regulation voltage is set by the voltage on the PWMLIMIT pin.

A low PWMLIMIT voltage will results in a low on-time for the internal power switch. The minimum duty factor of the switched mode power supply can be set to 0 %. The maximum duty factor is set to 75 %.

8.4 Bleeder for dimming applications

The SSL2102 IC contains some circuitry intended for mains dimmer compatibility. This circuit contains two current sinks that are called bleeders. A strong bleeder is used for zero-cross reset of the dimmer and TRIAC latching. A weak bleeder is added to maintain the hold current through the dimmer.

The strong bleeder switch is switched on when the maximum voltage on the WBLEED pin and the SBLEED pin is below the V_{th(SBLEED)} level (52 V typically). The weak bleeder switch is switched on as soon as the voltage on pin ISENSE exceeds the V_{th(high)(ISENSE)} level (-100 mV typically). The weak bleeder switch is switched off when the ISENSE voltage drops below the V_{th(low)(ISENSE)} level (-250 mV typically). The weak bleeder switch is also switched off when the strong bleeder switch is switched on. See Figure 5.



8.5 Valley switching

A new cycle is started when the primary switch is switched on (see <u>Figure 6</u>). After a time determined by the oscillator voltage, RC and the internal regulation level, the switch is turned off and the secondary stroke starts. The internal regulation level is determined by the voltage on pin PWMLIMIT.

After the secondary stroke, the drain voltage shows an oscillation with a frequency of approximately:

$$\frac{l}{2 \times \pi \times \sqrt{(L_p \times C_p)}}$$

(2)

where:

 L_p = primary self inductance C_p = parasitic capacitance on drain node As soon as the oscillator voltage is high again and the secondary stroke has ended, the circuit waits for a low drain voltage before starting a new primary stroke.

Figure 6 shows the drain voltage together with the valley signal, the signal indicating the secondary stroke and the RC voltage.

The primary stroke starts some time before the actual valley at low ringing frequencies, and some time after the actual valley at high ringing frequencies.



Figure 7 shows a typical curve for a reflected output voltage N at an output voltage of 80 V. This voltage is the output voltage transferred to the primary side of the transformer with the factor N (determined by the turns ratio of the transformer). It shows that the system switches exactly at minimum drain voltage for ringing frequencies of 480 kHz, thus reducing the switch-on losses to a minimum. At 200 kHz, the next primary stroke is started at 33 ° before the valley. The switch-on losses are still reduced significantly.

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8.6 Demagnetization

The system operates in discontinuous conduction mode if the AUX pin is connected. As long as the secondary stroke has not ended, the oscillator will not start a new primary stroke. During the first $t_{sup(xfmr_ring)}$ seconds, demagnetization recognition is suppressed. This suppression may be necessary in applications where the transformer has a large leakage inductance and at low output voltages.

8.7 Overcurrent protection

The cycle-by-cycle peak drain current limit circuit uses the external source resistor R_{SENSE}^{1} to measure the current. The circuit is activated after the leading edge blanking time t_{leb} . The protection circuit limits the source voltage over the R_{SENSE} resistor to $V_{th(ocp)SOURCE}$ and thus limits the primary peak current.

8.8 Short-winding protection

The short-winding protection circuit is also activated after the leading edge blanking time. If the source voltage exceeds the short-winding protection threshold voltage $V_{th(swp)SOURCE}$, the IC stops switching. Only a power-on reset will restart normal operation. The short-winding protection also protects in case of a secondary diode short circuit.

8.9 Overtemperature protection

Accurate temperature protection is provided in the device. When the junction temperature exceeds the thermal shut-down temperature, the IC stops switching. During thermal protection, the IC current is lowered to the start-up current. The IC continues normal operation as soon as the overtemperature situation has disappeared.

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^{1.} R_{SENSE} is the resistor between the SOURCE pin and GND

9. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are measured with respect to ground; positive currents flow into the device; pins V_{CC} and RC cannot be current driven. Pins ISENSE and AUX cannot be voltage driven.

Symbol	Parameter	Conditions	Min	Мах	Unit
Voltages		Conditions		шах	onic
Vonagoo	supply voltage	continuous	-0.4	+40	V
V _{RC}	voltage on pin RC		-0.4	+3	V
V _{RC2}	voltage on pin RC2		-0.4	+3	V
V _{BRIGHTNESS}	voltage on pin BRIGHTNESS		-0.4	+5	V
	voltage on pin PWMLIMIT		-0.4	+5	V
V _{PWMLIMIT}	0		-0.4	-	V
VSOURCE	voltage on pin SOURCE			+5	
V _{DRAIN}	voltage on pin DRAIN	DMOS power transistor; T _{amb} = 25 °C	-0.4	+600	V
V _{SBLEED}	voltage on pin SBLEED	off-state; T _j = 125 °C	-0.4	+600	V
		on-state; V _{VCC} > 8.5 V; T _j < 125 °C	-0.4	+16	V
V _{WBLEED}	voltage on pin WBLEED	off-state; T _j < 125 °C	-0.4	+600	V
		on-state; V _{VCC} > 8.5 V; T _j < 125 °C	-0.4	+12	V
Currents					
IISENSE	current on pin ISENSE		-20	+5	mA
I _{AUX}	current on pin AUX		-10	+5	mA
ISOURCE	current on pin SOURCE		-2	+2	А
I _{DRAIN}	current on pin DRAIN		-2	+2	А
General					
P _{tot}	total power dissipation	T _{amb} = 70 °C	-	1.6	W
T _{stg}	storage temperature		-55	+150	°C
T _{amb}	ambient temperature		-40	+100	°C
Tj	junction temperature		-40	+150	°C

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are measured with respect to ground; positive currents flow into the device; pins V_{CC} and RC cannot be current driven. Pins ISENSE and AUX cannot be voltage driven.

		y =			
Symbol	Parameter	Conditions	Min	Мах	Unit
V _{ESD} electrostatic discharge voltage	electrostatic discharge voltage	human body model;	<u>[1]</u>		
	Pins 20, 1, 4	-1000	+1000	V	
	All other pins	-2000	+2000	V	
	machine model	2 –200	+200	V	
		charged device model	<u>[3]</u> –500	+500	V

- [1] Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.
- [2] Machine model: equivalent to discharging a 200 pF capacitor through a 0.75 μ H coil and a 10 Ω series resistor.
- [3] Charged device model: equivalent to charging the IC up to 1 kV and the subsequent discharging of each pin down to 0 V over a 1 Ω resistor.

10. Thermal characteristics

The heat sink for SSL2102 applications is provided by the Printed-Circuit Board (PCB) copper. The SSL2102 uses thermal leads (pins 2, 3, 6, 7, 16, 17, 18 and 19) for heat transfer from the die to PCB.

Enhanced thermal lead connection may drastically reduce thermal resistance.

The following equation shows the relationship between the maximum allowable power dissipation P and the thermal resistance from junction to ambient.

$$R_{th(j-a)} = (T_{j(max)} - T_{amb})/P$$

Where:

R_{th(i-a)} = thermal resistance from junction to ambient

 $T_{i(max)}$ = maximum junction temperature

 T_{amb} = ambient temperature

P = power dissipation

The thermal resistance as a function of the PCB area (Board: 0.8 mm thickness, 2 layers, Bottom Cu coverage 90 %, Cu thickness 70 μ m

(390 W/mK), Core material conductivity: 0.5 W/mK, 10 vias dia 0.3 mm) is shown in Figure 8

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Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		[1] 62	KW

[1] Measured on a JEDEC test board (standard EIA/JESD 51-3) in free air with natural convection.

11. Characteristics

Table 6. Characteristics

 $T_{amb} = 25 \,^{\circ}C$; no overtemperature; all voltages are measured with respect to ground; currents are positive when flowing into the IC and PWMLIMIT and BRIGHTNESS pins are disconnected unless otherwise specified. Typical frequency 100 kHz.

-		-				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply						
I _{CC}	supply current	normal operation; V _{DRAIN} = 60 V; V _{CC} = 20 V	-	1.7	2	mA
I _{CC(ch)}	charge supply current	$V_{DRAIN} > 60 V;$ $V_{CC} = 0 V$	-6	-4.5	-	mA
V _{CC}	supply voltage		8.5	-	40	V
V _{CC(startup)}	start-up supply voltage		9.75	10.25	10.75	V
V _{CC(UVLO)}	undervoltage lockout supply voltage		7.9	8.2	8.5	V

Table 6. Characteristics ...continued

 $T_{amb} = 25 \,^{\circ}C$; no overtemperature; all voltages are measured with respect to ground; currents are positive when flowing into the IC and PWMLIMIT and BRIGHTNESS pins are disconnected unless otherwise specified. Typical frequency 100 kHz.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I _{DRAIN}	current on pin DRAIN	V _{DRAIN} > 60 V; no auxiliary supply	-	-	2.2	mA
		V _{DRAIN} > 60 V; with auxiliary supply	-	30	125	μΑ
V _{DRAIN}	voltage on pin DRAIN		40	-	600	V
Pulse width mo	odulator					
δ_{min}	minimum duty factor		-	0	-	%
δ_{max}	maximum duty cycle	f = 100 kHz	-	75	-	%
SOPS						
V _{det(demag)}	demagnetization detection voltage		50	100	150	mV
t _{sup(xfmr_ring)}	transformer ringing suppression time	at start of secondary stroke	1.0	1.5	2.0	μs
RC oscillator						
V _{RC(min)}	minimum voltage on pin RC		60	75	90	mV
V _{RC(max)}	maximum voltage on pin RC		2.4	2.5	2.6	V
$t_{ch(RC)}$	charge time on pin RC		-	1	-	μs
VBRIGHTNESS	voltage on pin BRIGHTNESS	2.5 V RC2 trip level	-	0.5	-	V
		180 mV RC2 trip level	-	1.25	-	V
		75 mV RC2 trip level	-	2.3	-	V
f _{osc}	oscillator frequency		10	100	200	kHz
IBRIGHTNESS	current on pin BRIGHTNESS	$V_{BRIGHTNESS} = 0 V$	-20	-24	-28	μΑ
Bleeder						
$V_{\text{th}(\text{SBLEED})}$	threshold voltage on pin SBLEED		46	52	56	V
$V_{th(low)} \\ ISENSE$	low threshold voltage on pin ISENSE		-	-250	-	mV
$V_{th(high)} \\ ISENSE$	high threshold voltage on pin ISENSE		-	-100	-	mV
$R_{DSon(SBLEED)}$	drain-source	$I_{SBLEED} = 25 \text{ mA}$				
	on-state resistance on pin	T _j = 25 °C	140	170	200	Ω
	SBLEED	T _j = 125 °C	220	270	320	Ω

Table 6. Characteristics ...continued

 $T_{amb} = 25 \,^{\circ}C$; no overtemperature; all voltages are measured with respect to ground; currents are positive when flowing into the IC and PWMLIMIT and BRIGHTNESS pins are disconnected unless otherwise specified. Typical frequency 100 kHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{DSon(WBLEED)}	drain-source	$I_{WBLEED} = 10 \text{ mA}$				
	on-state resistance on pin	$T_j = 25 \ ^{\circ}C$	250	310	350	Ω
	WBLEED	T _j = 125 °C	400	500	600	Ω
Duty factor reg	ulator: pin PWMLIM	NIT				
PWMLIMIT	current on pin PWMLIMIT		-25	-	-18	μA
V _{PWMLIMIT}	voltage on pin PWMLIMIT	maximum duty cycle = 3 V	-	3	-	V
		minimum duty factor threshold	-	0.45	-	V
Valley switchin	g					
$(\Delta V / \Delta t)_{vrec}$	valley recognition voltage change with time	minimum absolute value	<u>[1]</u> _	100	-	V/µs
f _{ring}	ringing frequency	$N \times V_O = 100 V$	200	550	800	kHz
t _{d(vrec-swon)}	valley recognition to switch-on delay time		-	150	-	ns
Current and sh	ort circuit winding	protection				
V _{th(ocp)} SOURCE	overcurrent protection threshold voltage on pin SOURCE	dV/dt = 0.1 V/µs	0.47	0.50	0.53	V
V _{th(swp)} SOURCE	short-winding protection threshold voltage on pin SOURCE	dV/dt = 0.1 V/µs	-	1.5	-	V
$t_{d(ocp-swoff)}$	delay time from overcurrent protection to switch-off	$dV/dt = 0.5 V/\mu s$	-	160	185	ns
t _{leb}	leading edge blanking time		250	350	450	ns
FET output sta	ge					
I _{L(DRAIN)}	leakage current on pin DRAIN	V _{DRAIN} = 600 V	-	-	125	μA
V _{BR(DRAIN)}	breakdown voltage on pin DRAIN	T _{amb} = 25 °C	600	-	-	V
R _{DSon}	drain-source	power switch; $I_{SOURCE} = $	–0.50 A			
	on-state resistance	T _j = 25 °C	4.50	6.5	7.5	Ω
		$I_{\text{SOURCE}} = -0.20 \text{ A}$				
		T _j = 125 °C	-	9.5	-	Ω

Table 6. Characteristics ...continued

 $T_{amb} = 25 \,^{\circ}C$; no overtemperature; all voltages are measured with respect to ground; currents are positive when flowing into the IC and PWMLIMIT and BRIGHTNESS pins are disconnected unless otherwise specified. Typical frequency 100 kHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
t _{f(DRAIN)}	fall time on pin DRAIN	input voltage: 300 V; no external capacitor at drain	-	75	-	ns		
Temperature p	Temperature protection							
T _{otp}	overtemperature protection trip	junction temperature	150	160	170	°C		
T _{otp(hys)}	overtemperature protection trip hysteresis	junction temperature	-	2	-	°C		

[1] Voltage change in time for valley recognition.



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12. Application information



13. Package outline



Fig 13. Package outline SOT163-1 (SO20)

14. Revision history

Table 7. Revision hist	Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
SSL2102_1	20090629	Product data sheet	-	-			

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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